



BC856BS

PNP GENERAL PURPOSE DUAL TRANSISTORS

VOLTAGE 65 Volts **POWER** 150 mWatts

FEATURES

- General purpose amplifier applications
- Collector current $I_c = 100\text{mA}$
- In compliance with EU RoHS 2002/95/EC directives

MECHANICAL DATA

Case: SOT-363, Plastic

Terminals: Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.006 gram

Marking :56S

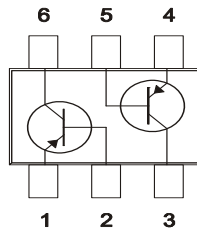
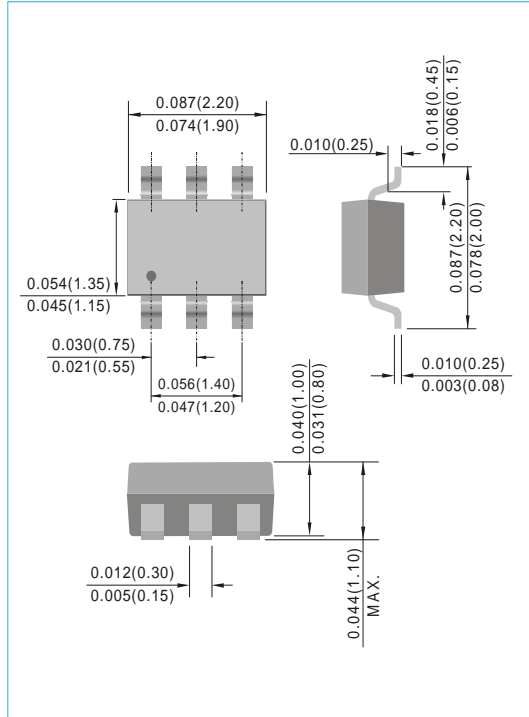


Fig.53

SOT-363

Unit : inch(mm)



ABSOLUTE RATINGS

Parameter	Symbol	Value	Units
Collector - Emitter Voltage	V_{CEO}	-65	V
Collector - Base Voltage	V_{CBO}	-80	V
Emitter - Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_c	-100	mA

THERMAL CHARACTERISTICS

Parameter	Symbol	Value	Units
Max .Total Power Dissipation	P_{TOT}	150	mW
Operating Junction Temperature and Storage Temperature range	T_J, T_{STG}	-55 to 150	°C



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ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Test Condition	MIN.	TYP.	MAX.	Units
Collector - Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -10\text{mA}$	-65	-	-	V
Collector - Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -10\mu\text{A}, V_{EB} = 0$	-80	-	-	V
Emitter - Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -1.0\mu\text{A}$	-5.0	-	-	V
Collector-Base Cutoff Current	I_{CBO}	$V_{CB} = -30\text{V}, I_E = 0$	-	-	-15	nA
DC Current Gain	h_{FE}	$I_C = -2.0\text{mA}, V_{CE} = -5\text{V}$	220	-	475	-
Collector - Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C = -10\text{mA}, I_B = -0.5\text{mA}$ $I_C = -100\text{mA}, I_B = -5.0\text{mA}$	-	-	-0.3 -0.65	V
Base - Emitter Saturation Voltage	$V_{BE(SAT)}$	$I_C = -10\text{mA}, I_B = -0.5\text{mA}$	-0.6	-	-0.9	V
Collector capacitance	C_{CB}	$V_{CB} = 10\text{V}, I_E = 0\text{A}$	-	1.9	-	pF
Emitter Capacitance	C_{EB}	$V_{EB} = 0.5\text{V}, I_C = 0\text{A}$	-	11	-	pF
Gain-Bandwidth Product	f_T	$V_{CE} = -5\text{V}, I_C = -10\text{mA}$ $f = 100\text{MHz}$	100	-	-	MHz



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ELECTRICAL CHARACTERISTICS CURVE

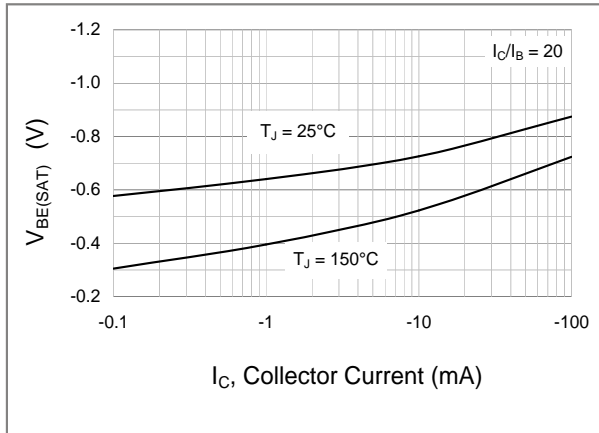


Fig.1 Base-Emitter Saturation Voltage VS Collector Current

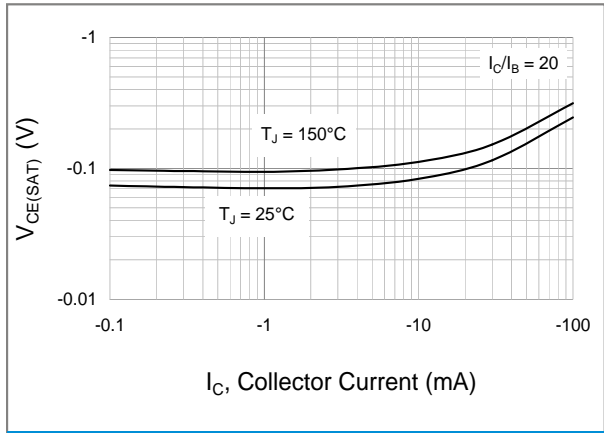


Fig.2 Collector-Emitter Saturation Voltage VS Collector Current

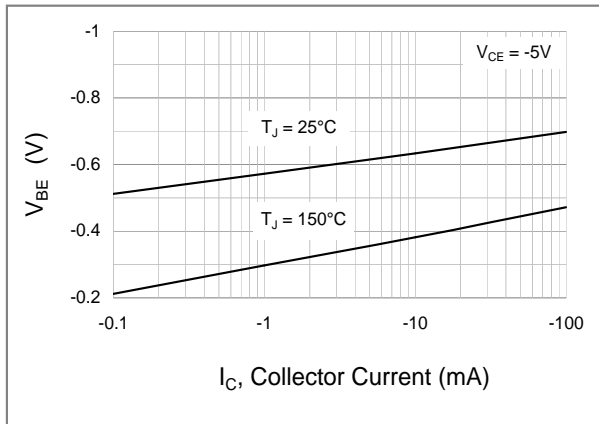


Fig.3 Base-Emitter Voltage VS Collector Current

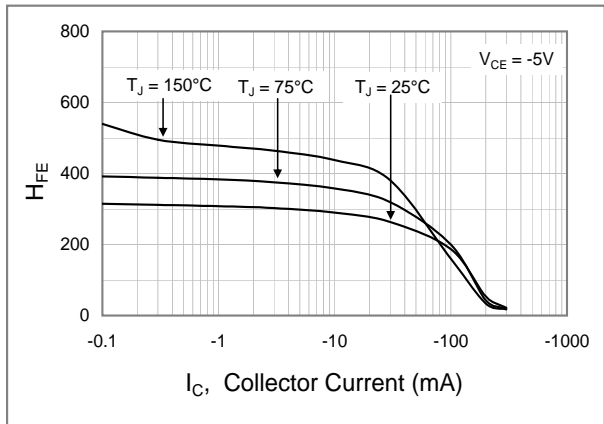


Fig.4 Typical DC Current Gain VS Collector Current

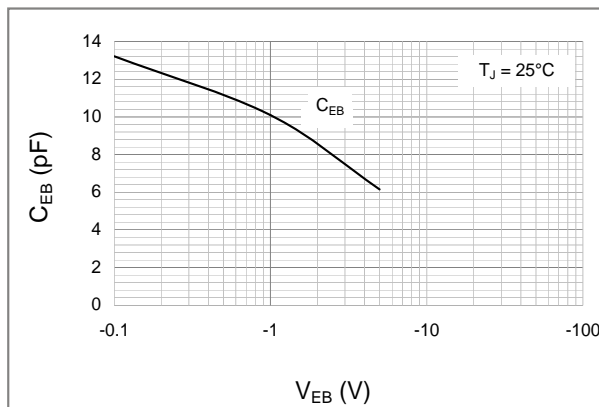


Fig.5 Emitter Capacitance VS Emitter-Base Voltage

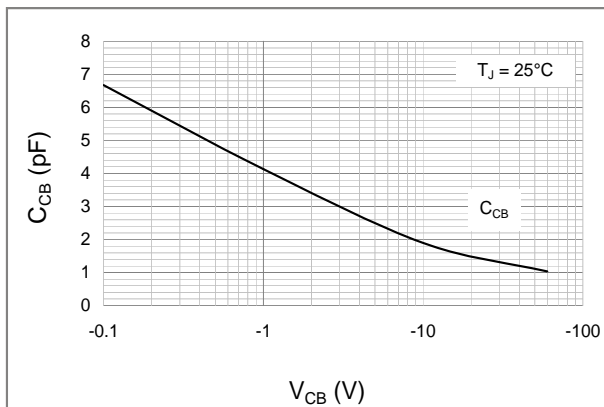
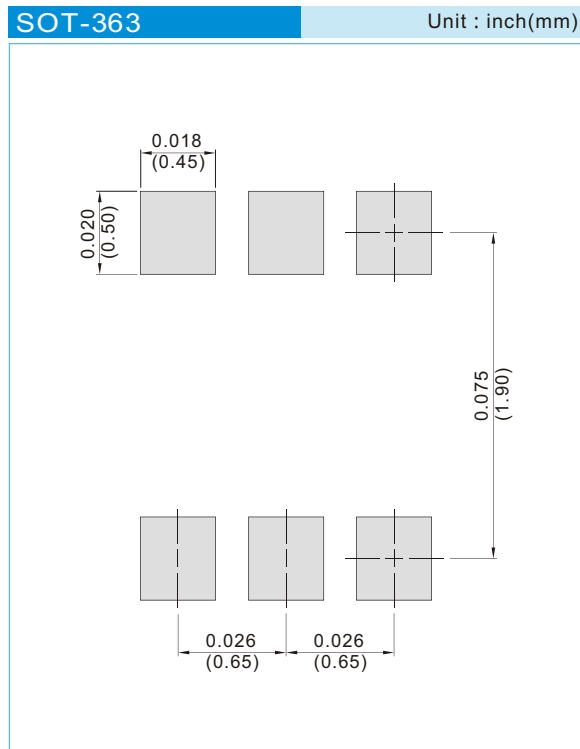


Fig.6 Collector Capacitance VS Collector-Base Voltage



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MOUNTING PAD LAYOUT



ORDER INFORMATION

- Packing information
 - T/R - 10K per 13" plastic Reel
 - T/R - 3K per 7" plastic Reel

LEGAL STATEMENT

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